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Note: xxxFW (JEDEC SOP) is not available in

Japan.

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

### TC74AC240P,TC74AC240F,TC74AC240FW,TC74AC240FT TC74AC244P,TC74AC244F,TC74AC244FW,TC74AC244FT

Octal Bus Buffer

TC74AC240P/F/FW/FT Ir C TC74AC244P/F/FW/FT N

Inverted, 3-State Outputs Non-Inverted, 3-State Outputs

The TC74AC240 and 244 are advanced high speed CMOS OCTAL BUS BUFFERs fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The 74AC240 is an inverting 3-state buffer while the 74AC244 is non-inverting. Both devices have two active-low output enables.

These devices are designed to be used in such applications as 3-state memory address drivers.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### Features

- High speed:  $t_{pd}$  = 4.0 ns (typ.) at V<sub>CC</sub> = 5 V DataSheet4U.com
- Low power dissipation:  $I_{CC} = 8 \mu A (max)$  at  $Ta = 25^{\circ}C$
- High noise immunity: V<sub>NIH</sub> = V<sub>NIL</sub> = 28% V<sub>CC</sub> (min)
- Symmetrical output impedance: |IOH| = IOL = 24 mA (min)Capability of driving 50  $\Omega$

transmission lines.

- $\bullet \quad Balanced \ propagation \ delays: \ t_pLH \simeq t_pHL$
- Wide operating voltage range: VCC (opr) = 2 to 5.5 V
- Pin and function compatible with 74F240/244

Weight	
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

 TC74AC240P, TC74AC244P

 UP20-P-300-2.54A

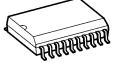
 TC74AC240F, TC74AC244F

 VICTUAL C244F

 SOP20-P-300-1.27A

 SOP20-P-300-1.27

 TC74AC240FW, TC74AC244FW



SOL20-P-300-1.27 TC74AC240FT, TC74AC244FT



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## TC74AC240,244P/F/FW/FT

20

19

18 1Y1

17

16 1Y2

15

14

13

12

11

V<sub>CC</sub>

2G

2A4

2A3

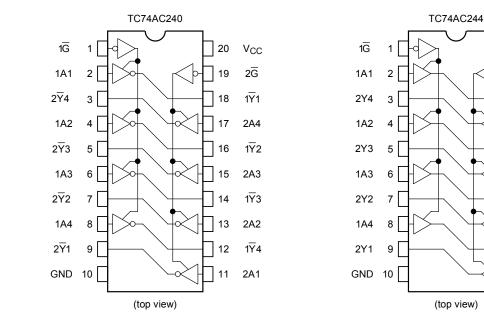
1Y3

2A2

1Y4

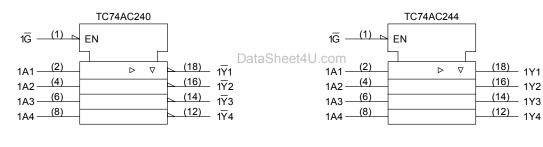
2A1

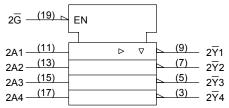
#### **Pin Assignment**

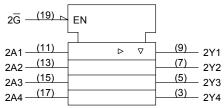


#### **IEC Logic Symbol**









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#### Truth Table

Inp	uts	Out	puts		
IG	An	Y <sub>n</sub> (244)	<u>Y</u> n (240)		
L	L	L	Н		
L	Н	Н	L		
Н	Х	Z	Z		

X: Don't care

Z: High impedance

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#### Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	IIК	±20	mA
Output diode current	I <sub>OK</sub>	±50	mA
DC output current	IOUT	±50	mA
DC V <sub>CC</sub> /ground current	ICC	±200	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

#### **Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	2.0 to 5.5	V
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	Vout	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub> Da	-40 to 85	°C
Input rise and fall time	dt/dV	0 to 100 (V <sub>CC</sub> = 3.3 ± 0.3 V)	ns/V
	u/uv	0 to 20 (V <sub>CC</sub> = 5 $\pm$ 0.5 V)	115/ V

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Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

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## **Electrical Characteristics**

#### **DC Characteristics**

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit	
		Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic	
					2.0	1.50	_	_	1.50	_	
High-level input voltage	VIH		_		3.0	2.10	_	_	2.10	—	V
					5.5	3.85	_	_	3.85	—	
					2.0	_	_	0.50	_	0.50	
Low-level input voltage	VIL		_		3.0	—	_	0.90	_	0.90	V
					5.5	—	—	1.65	—	1.65	
					2.0	1.9	2.0	_	1.9	_	
			I <sub>OH</sub> = -50 μA		3.0	2.9	3.0	_	2.9	—	
High-level output	Varia	V <sub>IN</sub> = V <sub>IH</sub> or			4.5	4.4	4.5	—	4.4	—	v
voltage	V <sub>OH</sub>	= VIH Or VIL	I <sub>OH</sub> = -4 mA		3.0	2.58	_	_	2.48	_	V
			I <sub>OH</sub> = −24 mA		4.5	3.94	_	_	3.80	—	
			I <sub>OH</sub> = −75 mA	(Note)	5.5	—	—	—	3.85	—	
	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>			2.0	_	0.0	0.1	_	0.1	v
			I <sub>OL</sub> = 50 μA		3.0	—	0.0	0.1	_	0.1	
Low-level output					4.5	—	0.0	0.1	—	0.1	
voltage			I <sub>OL</sub> = 12 mA		3.0	_	_	0.36	_	0.44	
			I <sub>OL</sub> = 24 mA		4.5	—	_	0.36	_	0.44	
			I <sub>OL</sub> = 75 mA	(Note)	5.5	—	—	—	_	1.65	
3-state output	I <sub>OZ</sub>		VIN = VIH or VIL		om 5.5	_	_	±0.5	_	±5.0	μA
off-state current	02	V <sub>OUT</sub> = V <sub>CC</sub> or GND								r	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	±0.1	_	±1.0	μA	
Quiescent supply current	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	8.0	_	80.0	μA	

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Note: This spec indicates the capability of driving 50  $\Omega$  transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

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#### AC Characteristics (C<sub>L</sub> = 50 pF, R<sub>L</sub> = 500 $\Omega$ , input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol Test Condition		Ta = 25°C			Ta = −40 to 85°C		Unit	
	,		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
Propagation delay	t <sub>pLH</sub>		3.3 ± 0.3	_	6.3	10.5	1.0	12.0	
time (Note 2)	t <sub>pHL</sub>	—	$5.0 \pm 0.5$	—	4.8	7.0	1.0	8.0	ns
Propagation delay	t <sub>pLH</sub>		$3.3 \pm 0.3$	_	7.0	11.4	1.0	13.0	ns
time (Note 3)	t <sub>pHL</sub>	—	$5.0 \pm 0.5$	—	5.2	7.5	1.0	8.5	
Output enable time	t <sub>pZL</sub>	—	$3.3 \pm 0.3$	_	8.4	14.0	1.0	16.0	ns
	t <sub>pZH</sub>		$5.0 \pm 0.5$	—	5.9	8.7	1.0	10.0	
Output disable time	t <sub>pLZ</sub>		$3.3 \pm 0.3$	_	6.4	10.5	1.0	12.0	ns
	t <sub>pHZ</sub>	—	$5.0 \pm 0.5$	—	5.5	7.9	1.0	9.0	
Input capacitance	CIN	—		_	5	10	_	10	pF
Output capacitance	C <sub>OUT</sub>	_		_	10	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>		(Note 1)		30	_		_	pF

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

I<sub>CC (opr)</sub> = C<sub>PD</sub>·V<sub>CC</sub>·f<sub>IN</sub> + I<sub>CC</sub>/8 (per bit)

Note 2: For TC74AC240 only

Note 3: For TC74AC244 only

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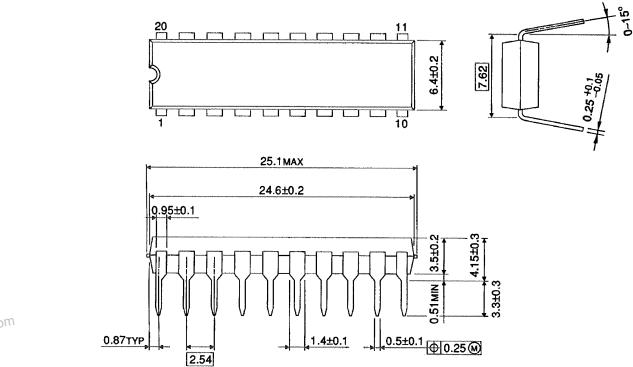
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#### Package Dimensions

DIP20-P-300-2.54A

Unit : mm



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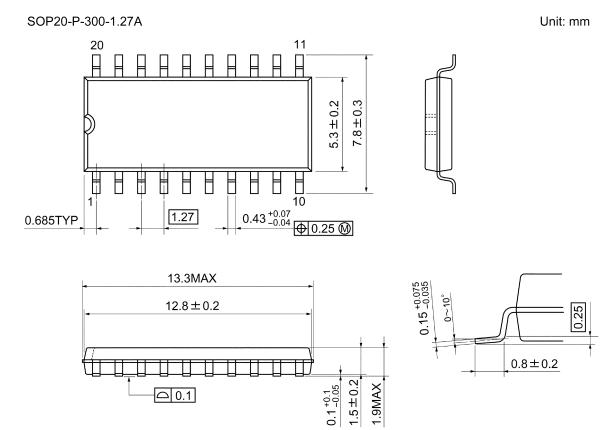
Weight: 1.30 g (typ.)

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### Package Dimensions



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Weight: 0.22 g (typ.)

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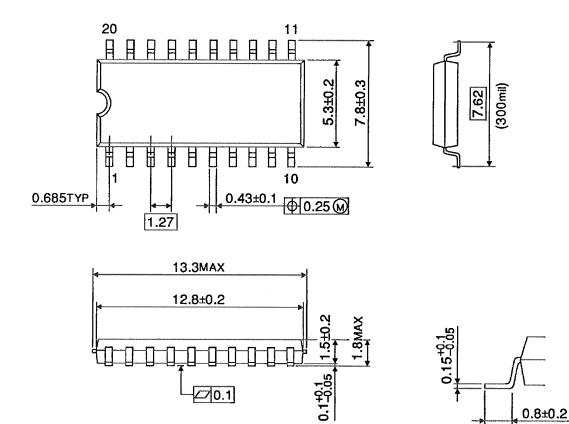
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## TC74AC240,244P/F/FW/FT

### Package Dimensions

SOP20-P-300-1.27

Unit : mm



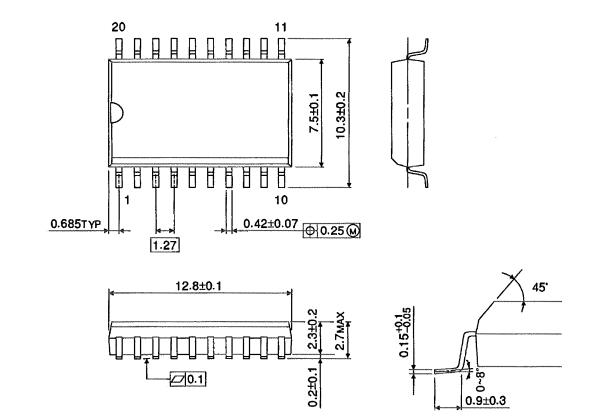
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Weight: 0.22 g (typ.)

## Package Dimensions (Note)

SOL20-P-300-1.27

Unit : mm



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Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

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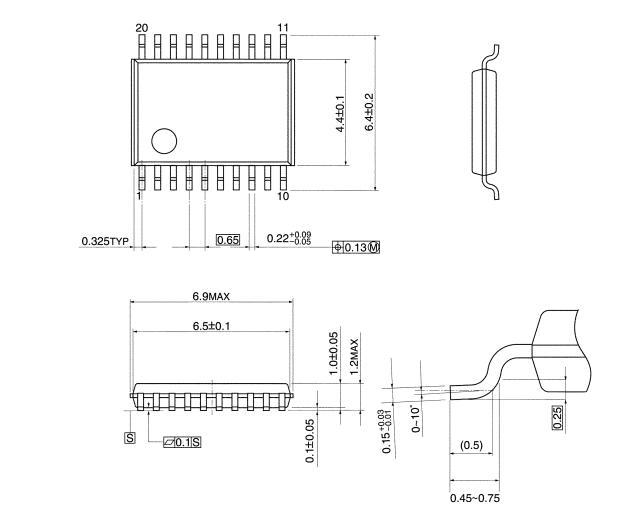
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## TC74AC240,244P/F/FW/FT

### Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



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Weight: 0.08 g (typ.)

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Note: Lead (Pb)-Free Packages DIP20-P-300-2.54A SOP20-P-300-1.27A TSSOP20-P-0044-0.65A

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